

#### **Features**

- ESD protection for one line with bi-directional
- Provide transient protection for the protected line to

IEC 61000-4-2 (ESD) ±15kV (air) / ±12kV (contact) IEC 61000-4-5 (Lightning) 4A (8/20µs)

- Ultra-low capacitance: 0.15pF typical
- For low operating voltage applications: 1.5V
   and below
- 0201 small DFN package saves board space
- Fast turn-on and low clamping voltage
- Solid-state silicon-avalanche and active circuit triggering technology
- Green part

## **Applications**

- Thunderbolt interface
- USB3.1 and USB3.0 interfaces
- USB Type-C interface
- DisplayPort interface
- Hand held portable applications
- Consumer electronics

## **Description**

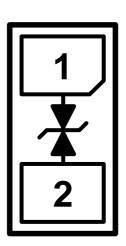
AZ5B8S-01F is a design which includes a bi-directional ESD rated clamping cell to protect high-speed data interfaces in an electronic system. The AZ5B8S-01F has been specifically designed to protect sensitive components which are connected to data and transmission lines from over-voltage caused by Electrostatic Discharging (ESD), Lightning, and Cable Discharge Event (CDE).

AZ5B8S-01F is a unique design which includes proprietary clamping cell with ultra-low capacitance in a small package. During transient conditions, the proprietary clamping cell prevents over-voltage on the control/data lines, protecting any downstream components.

AZ5B8S-01F is bi-directional and may be used on lines where the signal swings above and below ground.

AZ5B8S-01F may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15kV air, ±8kV contact discharge).

# Circuit Diagram / Pin Configuration



DFN0603P2Y (Bottom View) (0.6mm x 0.3mm x 0.3mm)

### **SPECIFICATIONS**

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C, unless otherwise specified)				
PARAMETER	SYMBOL	RATING	UNIT	
Peak Pulse Current (tp=8/20μs)	I <sub>pp</sub>	4	А	
Operating Supply Voltage	$V_{DC}$	±1.65	V	
ESD per IEC 61000-4-2 (Air)	V <sub>ESD-1</sub>	±15	kV	
ESD per IEC 61000-4-2 (Contact)	$V_{ESD-2}$	±12	KV	
Lead Soldering Temperature	T <sub>SOL</sub>	260 (10 sec.)	°C	
Operating Temperature	T <sub>OP</sub>	-55 to +125	°C	
Storage Temperature	T <sub>STO</sub>	-55 to +150	°C	

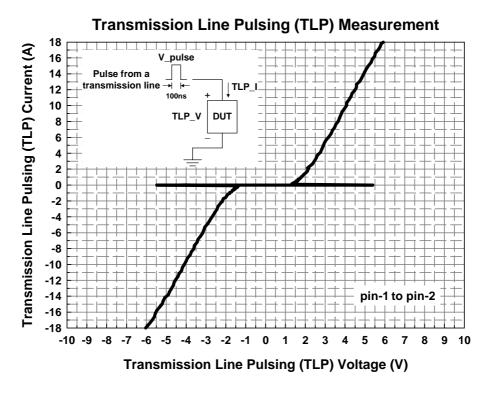
ELECTRICAL CHARACTERISTICS						
PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT
Reverse Stand-Off Voltage	$V_{RWM}$	T=25 °C.	-1.5		1.5	V
Reverse Leakage Current	I <sub>Leak</sub>	$V_{RWM} = \pm 1.5 V, T=25 ^{\circ}C.$			100	nA
Reverse Breakdown Voltage	$V_{BV}$	I <sub>BV</sub> = 10μA, T=25 °C.	4			V
ESD Clamping Voltage (Note 1)	$V_{\text{CL-ESD}}$	IEC 61000-4-2 +8kV (I <sub>TLP</sub> = 16A), Contact mode, T=25 °C.		5.5		V
ESD Dynamic Turn on Resistance	$R_{dynamic}$	IEC 61000-4-2 0~+8kV, Contact mode, T=25 °C.		0.25		Ω
Channel Input	C <sub>IN</sub>	$V_R = 1V$ , $f = 1MHz$ , $T=25$ °C.		0.18		pF
Capacitance	OIN	V <sub>R</sub> = 1V, f = 1GHz, T=25 °C.		0.15		pF

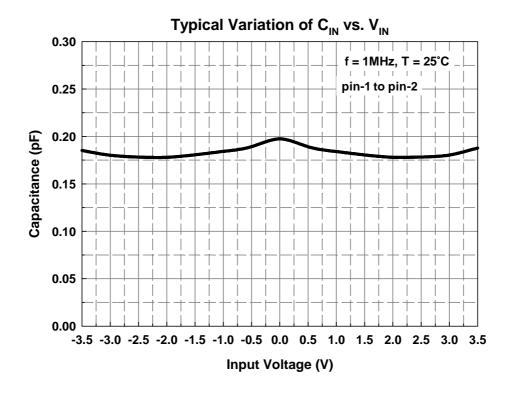
Note 1: ESD Clamping Voltage was measured by Transmission Line Pulsing (TLP) System.

TLP conditions:  $Z_0$ = 50 $\Omega$ ,  $t_p$ = 100ns,  $t_r$ = 1ns.



# **Typical Characteristics**







## **Application Information**

The AZ5B8S-01F is designed to protect one line against system ESD pulse by clamping it to an acceptable reference. It provides bi-directional protection.

The usage of the AZ5B8S-01F is shown in Fig. 1. Protected line, such as data line, control line, or power line, is connected at pin 1. The pin 2 is connected to a ground plane on the board. In order to minimize parasitic inductance in the board traces, all path lengths connected to the pins of AZ5B8S-01F should be kept as short as possible.

In order to obtain enough suppression of ESD induced transient, a good circuit board is critical. Thus, the following guidelines are recommended:

- Minimize the path length between the protected lines and the AZ5B8S-01F.
- Place the AZ5B8S-01F near the input terminals or connectors to restrict transient coupling.
- The ESD current return path to ground should be kept as short as possible.
- Use ground planes whenever possible.
- NEVER route critical signals near board edges and near the lines which the ESD transient easily injects to.

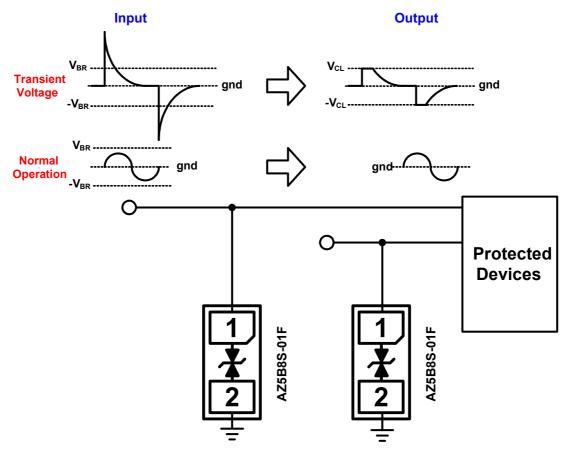
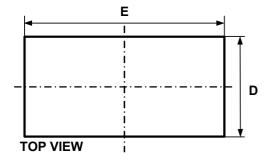


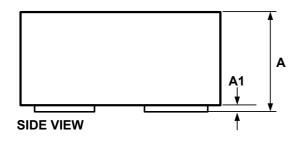
Fig. 1

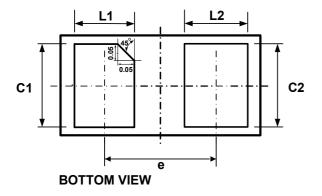


## **Mechanical Details**

# DFN0603P2Y PACKAGE DIAGRAMS

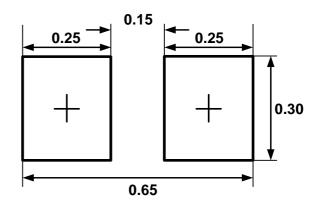






CVMDOL	MILLIMETERS			
SYMBOL	MIN.	NOM.	MAX.	
E	0.55	0.6	0.65	
D	0.25	0.3	0.35	
Α	0.28	0.3	0.32	
<b>A</b> 1	0	0.02	0.05	
L1	0.13	0.18	0.23	
L2	0.14	0.19	0.24	
C1/C2	0.2	0.25	0.3	
е		0.35 BSC		

### LAND LAYOUT



(Unit: mm)

#### Notes:

This LAND LAYOUT is for reference purposes only. Please consult your manufacturing partners to ensure your company's PCB design guidelines are met.

#### **MARKING CODE**



J = Device Code

Part Number	Marking Code
AZ5B8S-01F.R7G	ı
(Green Part)	J

Note. Green means Pb-free, RoHS, and Halogen free compliant.



**Ordering Information** 

PN#	Material	Type	Reel size	MOQ	MOQ/internal box	MOQ/carton
AZ5B8S-01F.R7G	Green	T/R	7 inch	12,000/reel	4 reels= 48,000/box	6 boxes =288,000/carton

**Revision History** 

Revision	Modification Description
Revision 2018/12/25	Formal Release.